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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 1

Complete if Known				
Application Number	10/676,969			
Filing Date	09/30/2003			
First Named Inventor	Gupta, et al.			
Group Art Unit	2814			
Examiner Name	Ngo, Ngan V.			
Attorney Docket Number	2003P12642US			

Examiner Initials*	1	U.S. Patent Document			Date of Publication of	Peges, Columns, Lines,
	Cits No.'	Number	(# known)	Name of Patentee or Applicant of Cited Document	Cited Document MMA-DD-YYYY	Where Relevant Pessages or Relevant Figures Appear
<del>pp</del>		6,274,979		Celii et al.		
7		6,580,213		Yamazaki		
44		6,588,764		Buechel et al.		
-	+ +					:

		OTHER NON PATENT LITERATURE DOCUMENTS	
Exeminer Initials*	Cits No.'	Include name of the earhor (in CAPITAL LETTERS), little of the cricies (when appropriate), little of the item (book, magazine, journal, serial, symposium, catalog, str.), data, page(t), volume-issue number(s), publisher, city antifor country where publishery where publishery where publishery where publishery.	1,3
hh	Α	S.M. Sze, "Physics of Semiconductor Devices", 2 <sup>nd</sup> Edition, 1981, Pgs. 270-273 and 516-531	
卢시	В	"Voltage Reduction in Organic Light-Emitting Diodes", L.S. Hung, M.G. Mason, Applied Physics Letters, Volume 78, Number 23, June 2, 2001, Pgs. 3732-3734	
hy	С	"Enhanced Hole Injection in a Bilayer Vacuum-Deposited Organic Light-Emitting Device Using a P-Type Doped Silicon Anode", X. Zhou, J. He, L. S. Liao, M. Lu, Z. H. Xiong, X.M. Ding, X. Y. Hou, F.G. Tao, C.E. Zhou and S.T. Lee, Applied Physics Letters, Volume 74, Number 4, January 25, 1999, Pgs. 609-611	

Examiner Signature	Mm M	Date Considered	3-18-05
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EXAMINER: Imital if reference dynsidered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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